

Features

- Solid-state silicon-avalanche technology
- 100 Watts Peak Pulse Power per Line ($t_p=8/20\mu s$)
- Low operating and clamping voltages
- Up to Four (4) Lines of Protection
- Working Voltages: 5 V
- Low Leakage Current

IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD) $\pm 15kV$ (air), $\pm 8kV$ (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 5.5A (8/20 μs)

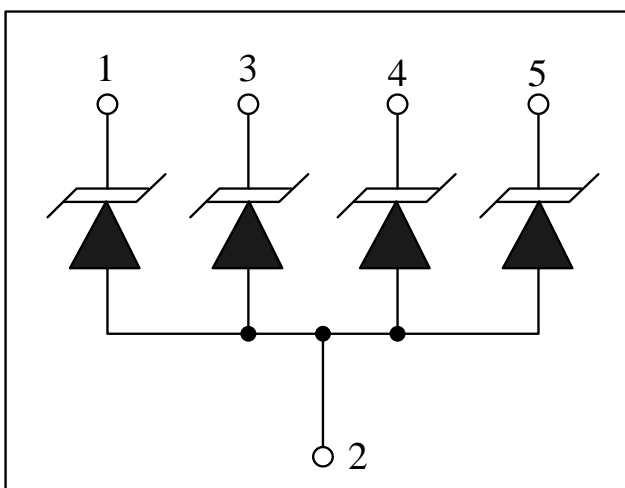
Mechanical Characteristics

- SOT-353 package
- Molding compound flammability rating: UL 94V-0
- Marking: Marking Code
- Packaging: Tape and Reel
- RoHS Compliant

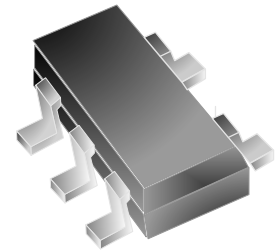
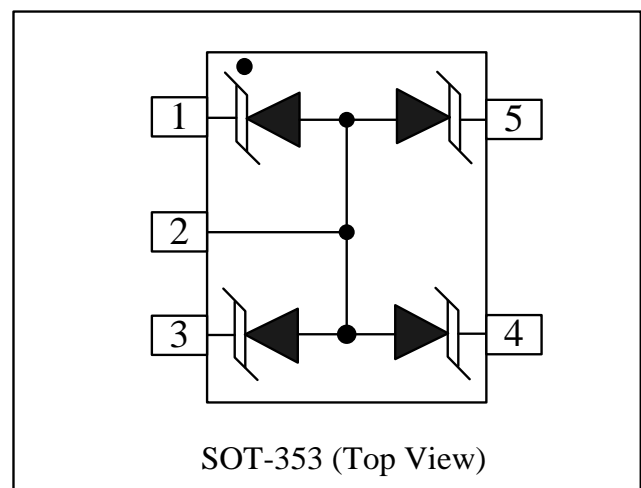
Applications

- Cellular Handsets & Accessories
- Personal Digital Assistants (PDAs)
- Notebooks & Handhelds
- Portable Instrumentation
- Digital Cameras
- MP3 Player

Circuit Diagram



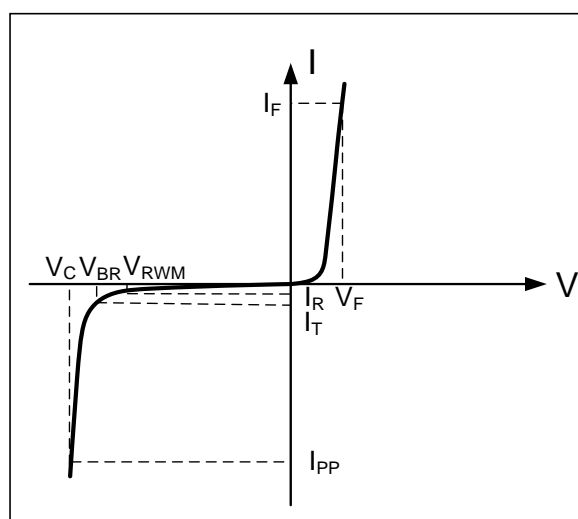
Schematic & PIN Configuration


SOT-353

Absolute Maximum Rating			
Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	100	W
Peak Forward Voltage ($I_F = 1A$, $t_p = 8/20\mu s$)	V_{FP}	1.5	V
Operating Temperature	T_J	-55 to + 125	$^{\circ}C$
Storage Temperature	T_{STG}	-55 to +150	$^{\circ}C$

Electrical Parameters (T=25 $^{\circ}C$)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_F	Forward Current
V_F	Forward Voltage @ I_F



Electrical Characteristics

WS05MF						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1mA$	6.0			V
Reverse Leakage Current	I_R	$V_{RWM} = 5V, T = 25^{\circ}C$			1	μA
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			5.5	A
Clamping Voltage	V_C	$I_{PP} = 1A, t_p = 8/20\mu s$			9.6	V
Clamping Voltage	V_C	$I_{PP} = 5.5A, t_p = 8/20\mu s$		15	18	V
Junction Capacitance	C_j	Between I/O pins and Ground $V_R = 0V, f = 1MHz$		22	25	pF

Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

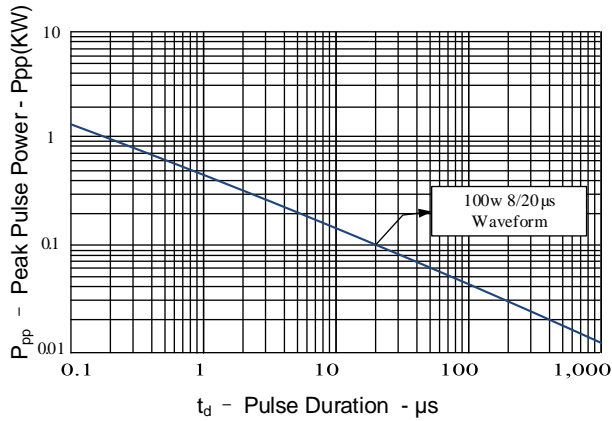


Figure 2: Power Derating Curve

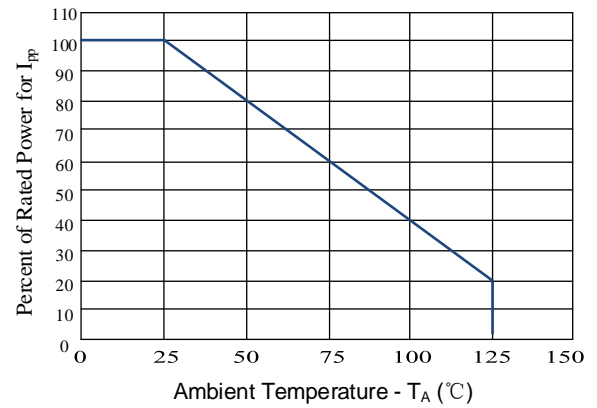


Figure 3: Clamping Voltage vs. Peak Pulse Current

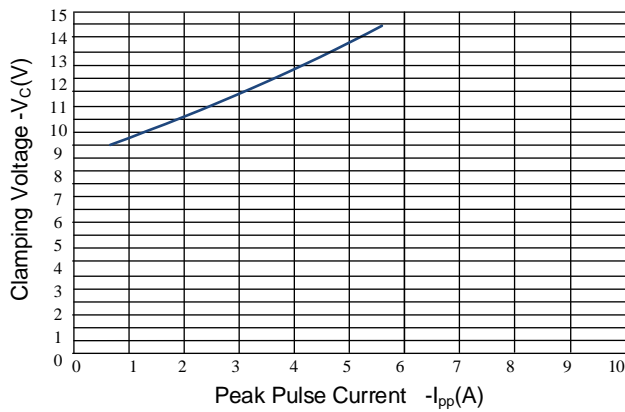


Figure 4: WS05MF Insertion Loss

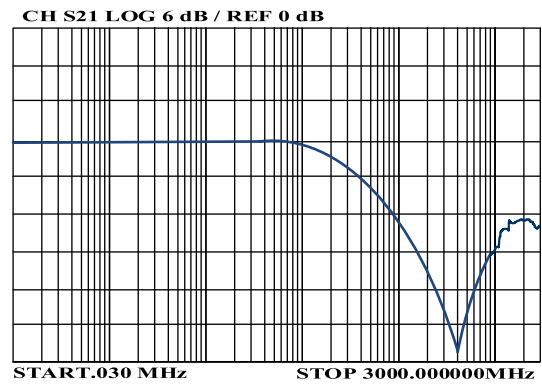


Figure 5: Normalized Junction Capacitance vs. Reverse Voltage

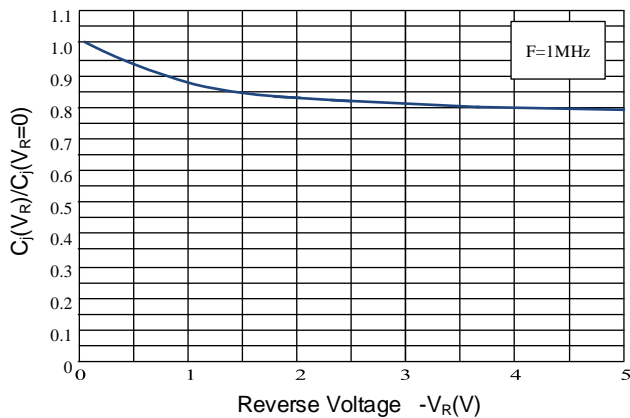
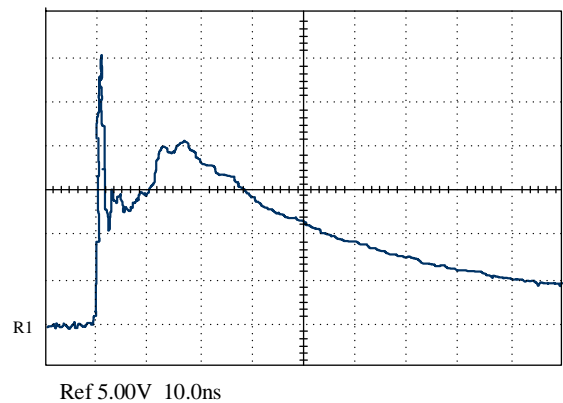
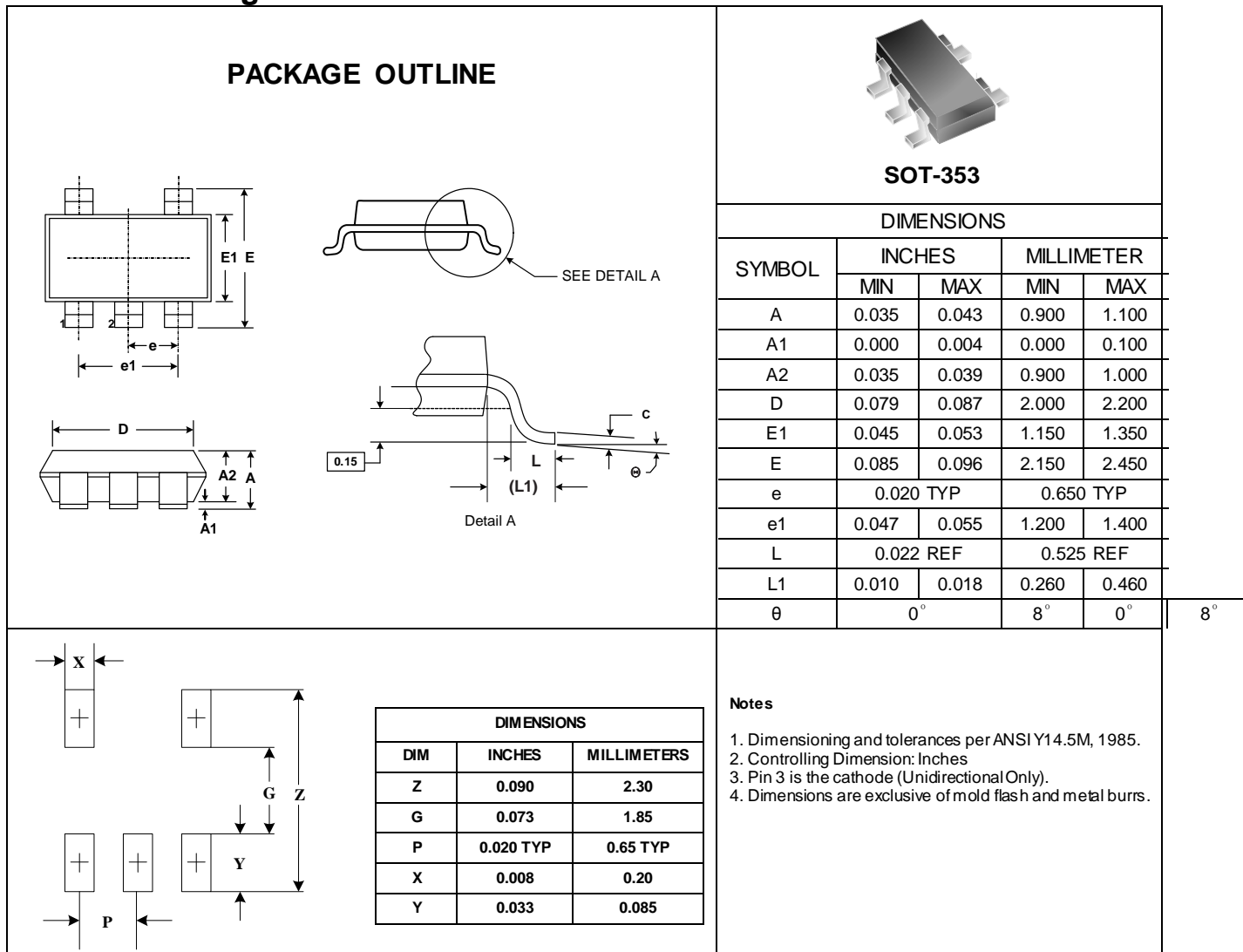


Figure 6: ESD Pulse Waveform (Per IEC 61000-4-2)



Outline Drawing – SOT-353



Marking Codes

Part Number	WS05MF
Marking Code	05F

Package Information

Qty: 3k/Reel

CONTACT INFORMATION

CYG WAYON CIRCUIT PROTECTION CO., LTD.

No.1001, Shiwan (7) Road, Pudong District, Shanghai, P.R.China.201202

Tel: 86-21-68969993 Fax: 86-21-50757680 Email: market@way-on.comWAYON website: <http://www.way-on.com>

For additional information, please contact your local Sales Representative.

CYWAYON® is registered trademark of Wayon Corporation.

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.